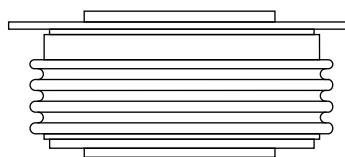


Standard Recovery Diodes (Hockey PUK Version), 1200A

FEATURES

- Wide current range
- High voltage ratings up to 4000V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style DO-200AC(K-PUK), Nell's D-type Capsule
- Lead (Pb)-free



TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

DO-200AC(K-PUK)
(Nell's D-type Capsule)

PRODUCT SUMMARY	
I _{F(AV)}	1200A

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNIT
I _{F(AV)}		1200	A
	T _{hs}	55	°C
I _{F(RMS)}		2040	A
	T _{hs}	25	°C
I _{FSM}	50 HZ	12200	A
	60 HZ	12800	
I ² t	50 HZ	744	kA ² s
	60 HZ	680	
V _{RRM}		2400 to 4000	V
T _J	Typical	-40 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} , MAXIMUM AT T _J = T _J MAXIMUM mA
D1200D	24	2400	2500	50
	30	3000	3100	
	36	3600	3700	
	40	4000	4100	

FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNIT	
Maximum average forward current at heatsink temperature	$I_{F(AV)}$	180° conduction, half sine wave Double side (single side) cooled			1200(550)	A	
					55 (85)	°C	
Maximum RMS forward current	$I_{F(RMS)}$	25°C heatsink temperature double side cooled			2040	A	
Maximum peak, one cycle non-repetitive surge current	I_{FSM}	$t = 10\text{ms}$	No voltage reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	12200	A	
		$t = 8.3\text{ms}$	12800				
		$t = 10\text{ms}$	50% V_{RRM} reapplied		10290		
		$t = 8.3\text{ms}$	10750				
Maximum I^2t for fusing	I^2t	$t = 10\text{ms}$	No voltage reapplied	Initial $T_J = T_J$ maximum	744	kA^2s	
		$t = 8.3\text{ms}$	680				
		$t = 10\text{ms}$	50% V_{RRM} reapplied		529		
		$t = 8.3\text{ms}$	480				
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1 \text{ to } 10 \text{ ms, no voltage reapplied}$			7442	$\text{kA}^2\sqrt{\text{s}}$	
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}, T_J = T_J \text{ maximum})$			1.06	V	
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)}, T_J = T_J \text{ maximum})$			1.18		
Low level value of forward slope resistance	r_{t1}	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}, T_J = T_J \text{ maximum})$			0.44	$\text{m}\Omega$	
High level value of forward slope resistance	r_{t2}	$(I > \pi \times I_{F(AV)}, T_J = T_J \text{ maximum})$			0.41		
Maximum forward voltage drop	V_{FM}	$I_{pk} = 2000\text{A}, T_J = T_J \text{ maximum, } t_p = 10 \text{ ms sinusoidal wave}$			1.95	V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNIT
Maximum junction operating temperature range	T_J				-40 to 150	°C
Maximum storage temperature range	T_{stg}				-55 to 200	
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled			0.073	K/W
		DC operation double side cooled			0.031	
Mounting force, ±10%					14700 (1500)	N (kg)
Approximate weight					250	g
Case style		DO-200AC (K-PUK), Nell's D-type Capsule				

△ R_{thJc} CONDUCTION						
CONDUCTION ANGEL	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDUCTIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum	K/W
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

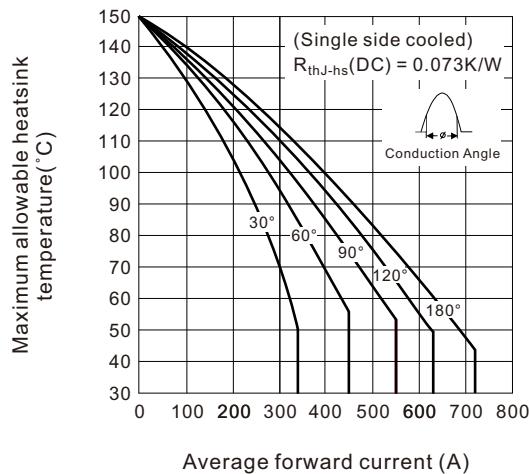
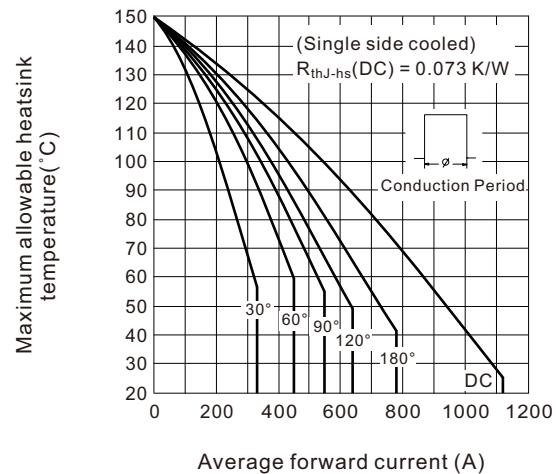
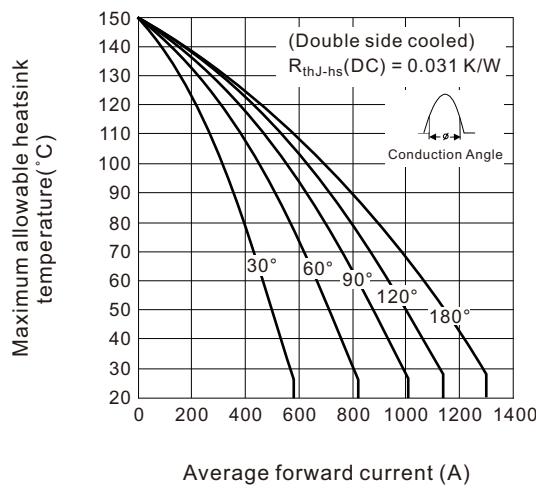
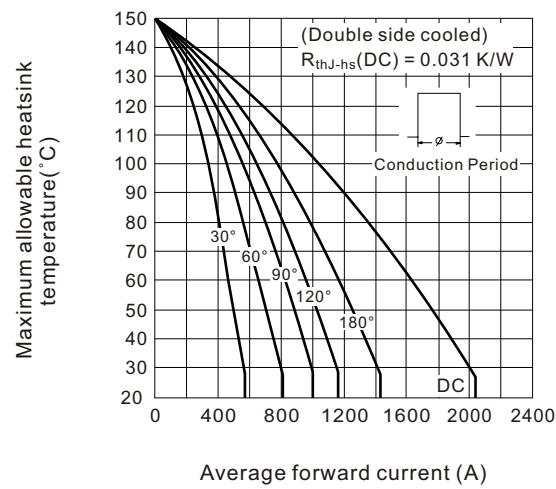
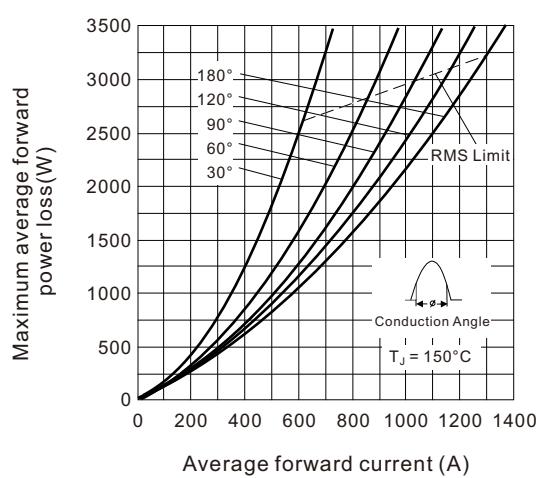
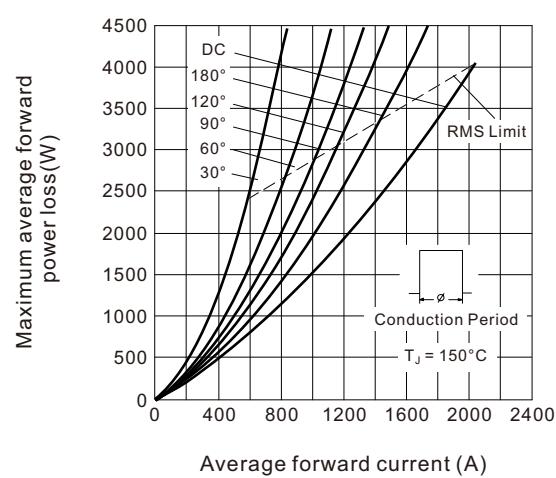
Fig.1 Current ratings characteristics

Fig.2 Current ratings characteristics

Fig.3 Current ratings characteristics

Fig.4 Current ratings characteristics

Fig.5 Forward power loss characteristics

Fig.6 Forward power loss characteristics


Fig.7 Maximum non-repetitive surge current single and double side cooled

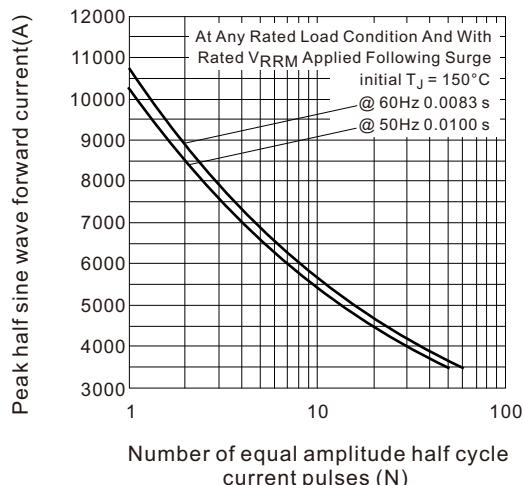


Fig.8 Maximum non-repetitive surge current single and double side cooled

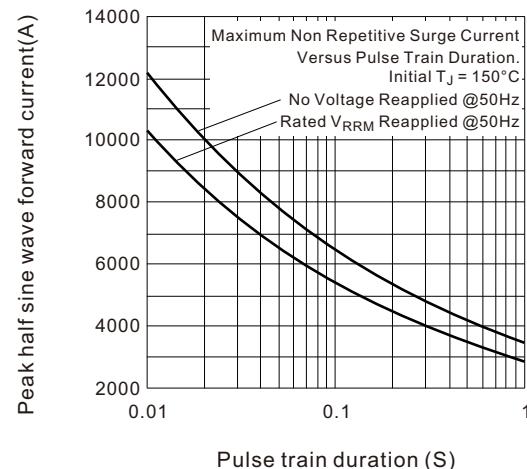


Fig.9 Forward voltage drop characteristics

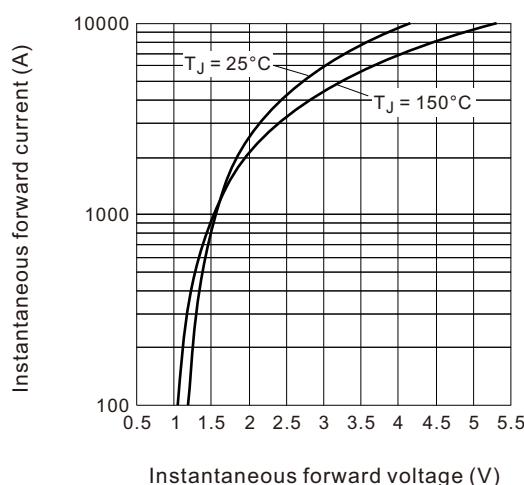
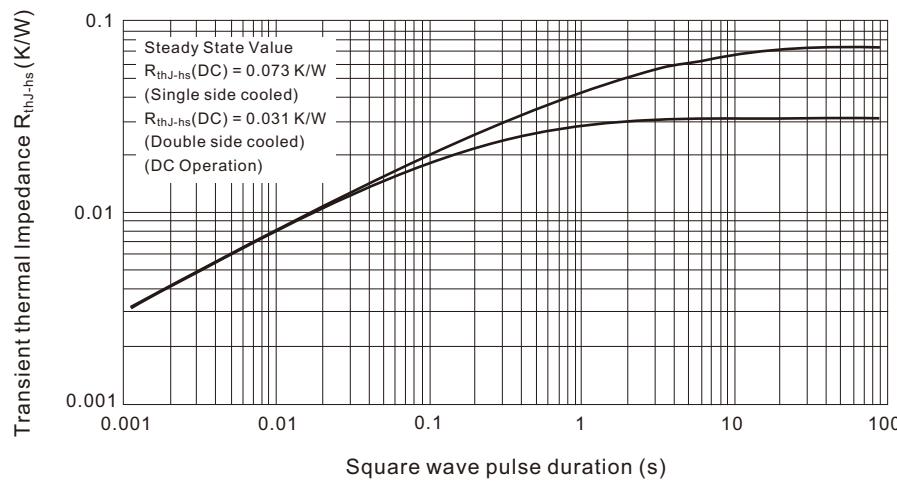
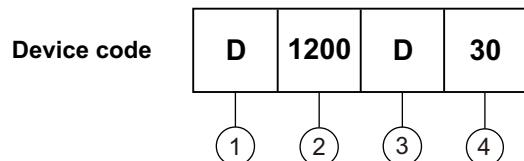


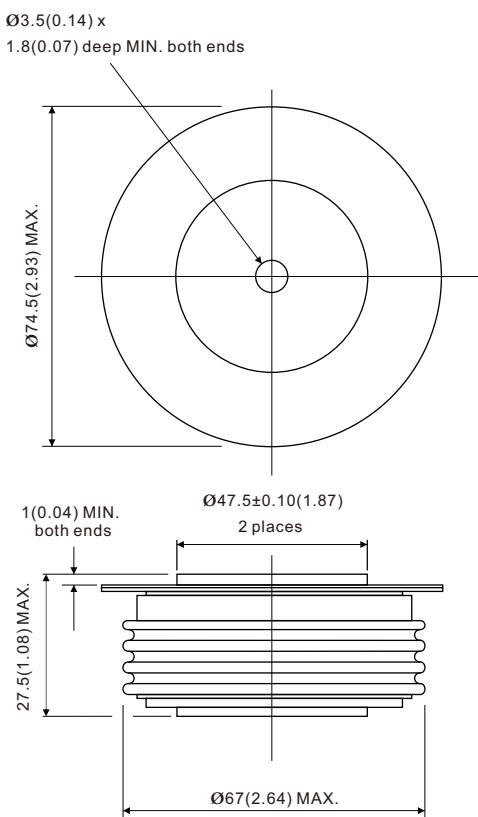
Fig.10 Thermal Impedance R_{thJ-hs} characteristics



ORDERING INFORMATION TABLE



- [1] - "D" for standard recovery diode
- [2] - Maximum average forward current, "1200" for 1200A
- [3] - Case style : "D" for Nell's D-type Capsule, DO-200AC (K-PUK)
- [4] - Voltage code, code x 100 = V_{RRM}

DO-220AC (K-PUK), Nell's D-type Capsule


All dimensions in millimeters (inches)

K
A